

UF3055-Q

Power MOSFET

3.0A, 60V N-CHANNEL ENHANCEMENT MODE POWER MOSFET

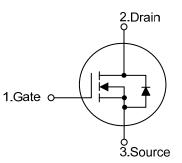
DESCRIPTION

As an N-channel enhancement mode power MOSFET, the UTC **UF3055-Q** is designed for low voltage, high speed switching applications in power supplies, converters and power motor controls and bridge circuits.

FEATURES

* $R_{DS(ON)}$ < 0.14 Ω @ V_{GS} =10 V, I_D =1.5A

SYMBOL



1 TO-252

ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing	
Lead Free	Halogen Free	Fackage	1	2	3	Facking	
UF3055L-TN3-R	UF3055G-TN3-R	TO-252	G	D	S	Tape Reel	
Note: Pin Assignment: G: G	ate D: Drain S: Source						
UF3055 <u>G-TN3-R</u>	(1) R: Tape Reel (2) TN3: TO-252						
	(3) G: Halogen Free and Lead Free L: Lead Free						
■ MARKING UTC UTC L: Lead Free G: Halogen Free Data Code 1 Www.unisonic.com.tw 1 of 5 Comparing by @ 2017 Unisonia Tagbaalogia Co. Ltd							
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ABSOLUTE MAXIMUM RATING (T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		V _{DSS}	60	V	
Gate-Source Voltage		V _{GSS}	±20	V	
Drain Current	Continuous	I _D	3	А	
	Pulsed (Note 2)	I _{DM}	I _{DM} 9		
Avalanche Energy (Note 3)	Single Pulsed (Note 3)	E _{AS}	45	mJ	
Peak Diode Recovery dv/dt (Note	e 4)	dv/dt 15.4		V/ns	
Power Dissipation		PD	20	W	
Junction Temperature		TJ +150		°C	
Storage Temperature Range		T _{STG}	-55 ~ +150	°C	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3. L = 3.0 mH, I_{AS} = 5.5 A, V_{DD} = 50 V, R_G = 25 Ω , Starting T_J = 25°C.

4. $I_{SD} \le 3.0$ A, di/dt ≤ 200 A/µs, $V_{DD} \le V_{(BR)DSS}$, $T_J = 25^{\circ}C$.

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ _{JA}	110	°C/W	
Junction to Case	$\theta_{\rm JC}$	6.3	°C/W	

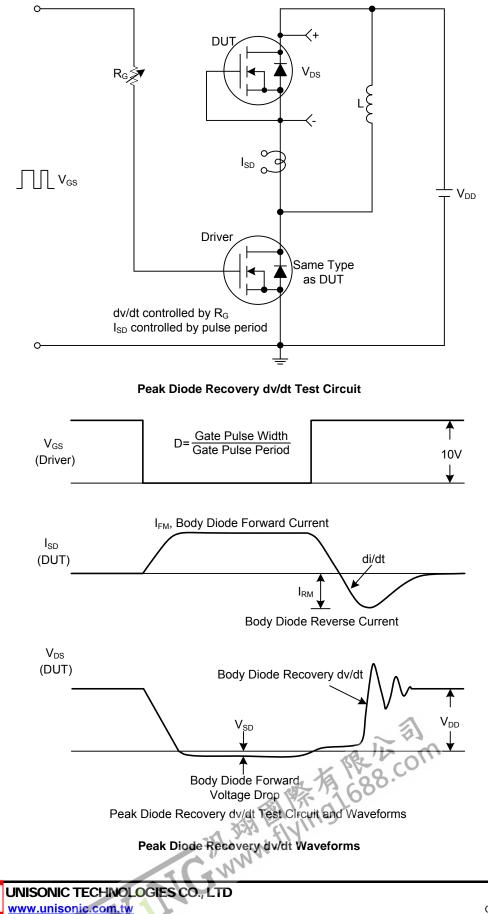
ELECTRICAL CHARACTERISTICS (T_J =25°C, unless otherwise specified)

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PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0V, I _D =250µA	60			V
Drain-Source Leakage Current	I _{DSS}	V _{GS} =0V, V _{DS} =60V			1	μA
Gate-Source Leakage Current	I _{GSS}	V_{GS} = ±20 V, V_{DS} =0V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} =V _{DS} , I _D =250µA	2.0		4.0	V
Static Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10 V, I _D =1.5A			0.14	Ω
DYNAMIC PARAMETERS						
Input Capacitance	CISS			250		рF
Output Capacitance	C _{OSS}	V _{GS} =0 V, V _{DS} =25 V, f=1.0MHz		70		рF
Reverse Transfer Capacitance	C _{RSS}			15		рF
SWITCHING PARAMETERS						
Total Gate Charge (Note 1)	Q_{G}			11.3		nC
Gate-Source Charge	Q_{GS}	V _{DS} =48V, V _{GS} =10V, I _D =3.0A, I _G =1mA (Note 1, 2)		5.7		nC
Gate-Drain Charge	Q_{GD}	IG = IIIA (INOLE 1, 2)		1.8		nC
Turn-ON Delay Time (Note 1)	t _{D(ON)}			2.6		ns
Turn-ON Rise Time	t _R	V _{DD} =30V, V _{GS} =10V, I _D =3.0A,		15.2		ns
Turn-OFF Delay Time	t _{D(OFF)}	R _G =25Ω (Note 1, 2)		3.4		ns
Turn-OFF Fall-Time	t _F			2.8		ns
DRAIN-SOURCE DIODE CHARACTERIS	TICS AND	MAXIMUM RATINGS				
Maximum Body-Diode Continuous Current	I _S				3.0	А
Maximum Body-Diode Pulsed Current	I _{SM}		5		12	А
Diode Forward Voltage (Note 1)	V_{SD}	I _S =3.0A, V _{GS} =0V	-01		1.4	V
Reverse Recovery Time (Note 1)	t _{rr}	I _S =3.0A, V _{GS} =0V,		40		nS
Reverse Recovery Charge	Q _{rr}	dl _F /dt =100A/µs		56		nC
Notes: 1 Pulse Test : Pulse width < 300us	Duty cycl	p < 2%				

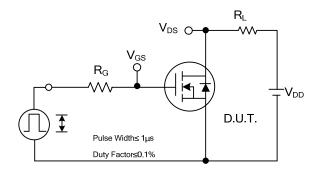
Notes: 1. Pulse Test : Pulse width \leq 300µs, Duty cycle \leq 2%.

2. Essentially independent of operating ambient temperature. NNN.

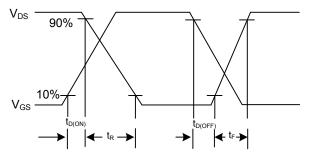
TEST CIRCUITS AND WAVEFORMS



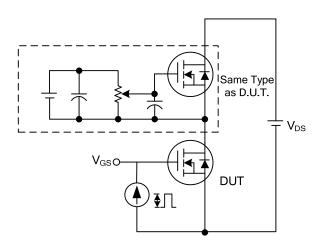
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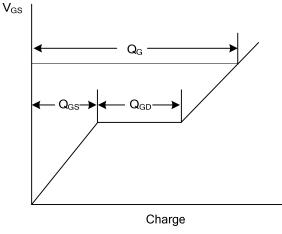


Switching Test Circuit



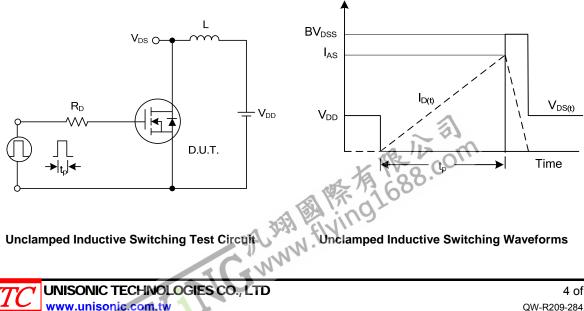
Switching Waveforms





Gate Charge Test Circuit

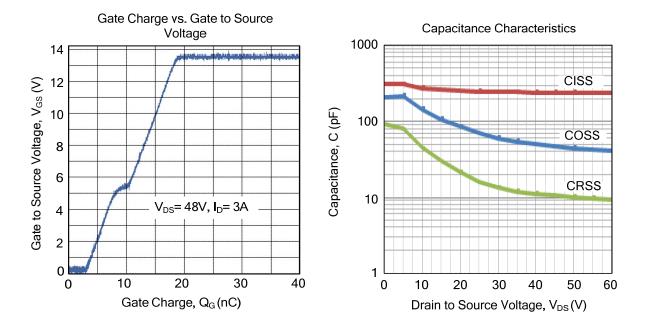
Gate Charge Waveform



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TYPICAL CHARACTERISTICS



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